

# 8/7/6/5/4/3/2/1-Phase Synchronous-Rectified Buck Controller for Next Generation GPU Core Power

# **General Description**

The uP9511R is an 8/7/6/5/4/3/2/1-phase PWM controller specifically designed to provide high-precision output voltage system for next generation GPUs. The uP9511R provides programmable output voltage and active voltage positioning functions to adjust the output voltage as a function of the load current, so it is optimally positioned for a load current transient.

The uP9511R supports NVIDIA Open Voltage Regulator 8 with PWMVID feature. The PWMVID input is buffered and filtered to generate accurate reference voltage and the output voltage is precisely regulated to the reference input.

The uP9511R adopts continuous total DCR current sensing for load line programming. The uP9511R provides hardware setting to adjust the operating phase number in different load current state. The uP9511R uses MOSFET  $R_{\rm DS(ON)}$  current sensing for channel current balance.

Other features include adjustable soft-start, channel current limit, under voltage protection, over voltage protection and power good output. The uP9511R is available in VQFN5x5-40L package.

# Ordering Information

Order Number	Package	Top Marking
uP9511RQGJ	VQFN5x5 - 40L	uP9511R

#### Note:

- (1) Please check the sample/production availability with uPI representatives.
- (2) uPI products are compatible with the current IPC/ JEDEC J-STD-020 requirements. They are halogen-free, RoHS compliant and 100% matte tin (Sn) plating that are suitable for use in SnPb or Pb-free soldering processes.

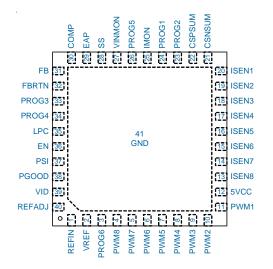
#### . Features

- Support NVIDIA's Open VReg Type 8 PWMVID Technology
- Selectable 8/7/6/5/4/3/2/1-Phase Operation by Hardware Setting
- Differential Remote Voltage Sensing
- Continuous Inductor DCR Current Sensing Voltage Adjustment
- Switching Frequency Adjustment
- Operating Phase Number Adjustment
- □ Adjustable Current Balancing by R<sub>DS(ON)</sub> Current Sensing
- Adjustable Soft-Start
- Optimize for Phase Extension Application
- Channel Current Limit Protection
- Over/Under Voltage Protection
- Over Temperature Protection
- RoHS Compliant and Halogen Free

# Applications

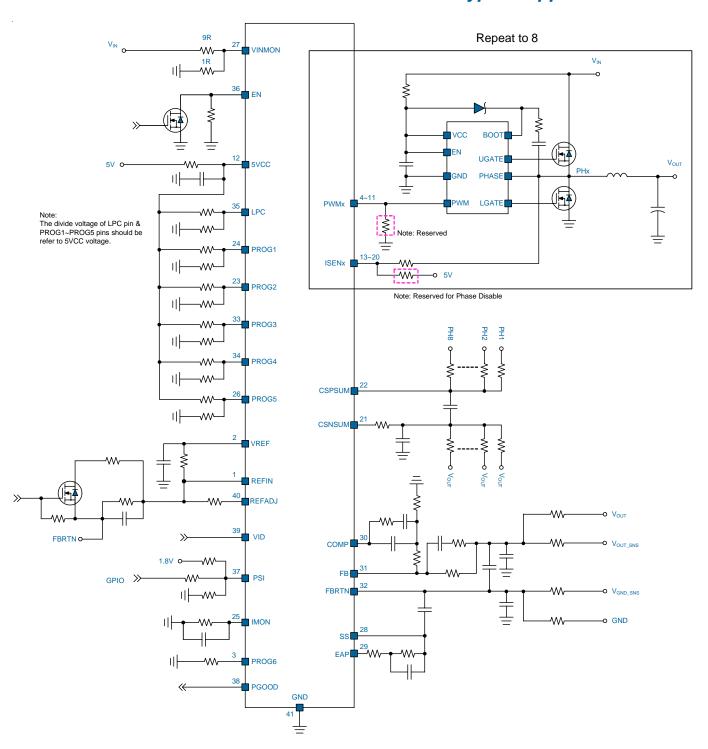
Middle-High End GPU Core Power Supplies

# Pin Configuration





# Typical Application Circuit





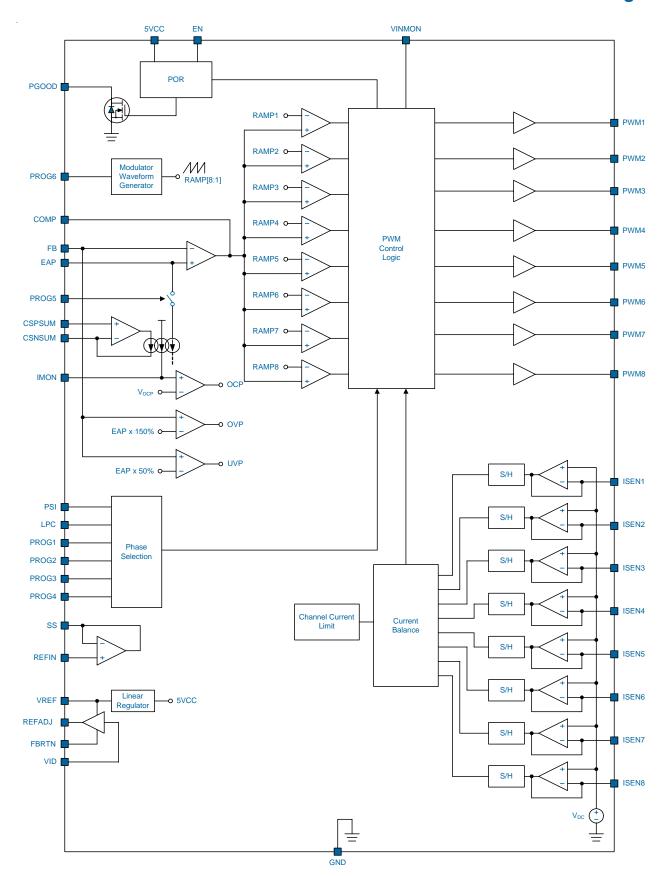
1 2 3 4	REFIN VREF	Reference Input. Connect this pin to an external reference voltage through a resistor or connect to the output of the REFADJ circuit.  Reference Voltage. 2V LDO voltage output pin. Connect an at least 1 uF decoupling
3		Reference Voltage, 2V LDO voltage output pin, Connect an at least 1 uF decoupling
		capacitor between this pin and GND.
4	PROG6	Function Setting Pin 6. Connect a resistor from this pin to GND to set the switching frequency.
	PWM8	Phase 8 PWM Output. Connect this pin to the PWM input of external MOSFET driver.
5	PWM7	Phase 7 PWM Output. Connect this pin to the PWM input of external MOSFET driver.
6	PWM6	Phase 6 PWM Output. Connect this pin to the PWM input of external MOSFET driver.
7	PWM5	Phase 5 PWM Output. Connect this pin to the PWM input of external MOSFET driver.
8	PWM4	Phase 4 PWM Output. Connect this pin to the PWM input of external MOSFET driver.
9	PWM3	Phase 3 PWM Output. Connect this pin to the PWM input of external MOSFET driver.
10	PWM2	Phase 2 PWM Output. Connect this pin to the PWM input of external MOSFET driver.
11	PWM1	Phase 1 PWM Output. Connect this pin to the PWM input of external MOSFET driver.
12	5VCC	Supply Input for the IC. Connect this pin to a 5V voltage source with a $2.2\Omega$ + 1uF filter.
13	ISEN8	ISEN8. Connect this pin to the PHASE8 pin with a resistor to sense phase 8 output current.
14	ISEN7	ISEN7. Connect this pin to the PHASE7 pin with a resistor to sense phase 7 output current.
15	ISEN6	ISEN6. Connect this pin to the PHASE6 pin with a resistor to sense phase 6 output current.
16	ISEN5	ISEN5. Connect this pin to the PHASE5 pin with a resistor to sense phase 5 output current.
17	ISEN4	ISEN4. Connect this pin to the PHASE4 pin with a resistor to sense phase 4 output current.
18	ISEN3	ISEN3. Connect this pin to the PHASE3 pin with a resistor to sense phase 3 output current.
19	ISEN2	ISEN2. Connect this pin to the PHASE2 pin with a resistor to sense phase 2 output current.
20	ISEN1	ISEN1. Connect this pin to the PHASE1 pin with a resistor to sense phase 1 output current.
21	CSNSUM	Inverting Input of Total Current Sense Amplifier.
22	CSPSUM	Non-Inverting Input of Total Current Sense Amplifier.
23	PROG2	Function Setting Pin 2. Connect this pin to the 5VCC with a voltage divider to set the phase reduction threshold and hysteresis.
24	PROG1	Function Setting Pin 1. Connect this pin to the 5VCC with a voltage divider to set the phase reduction threshold and hysteresis.
25	IMON	Output Current Monitor. The output current of this pin is proportional to the total load current. The total load current is sensed and flows out of this pin, and a resistor from this pin to GND makes the IMON voltage proportional to the total output current. A capacitor can be connected from IMON to GND to adjust the response time of IMON.
26	PROG5	Function Setting Pin 5. Connect this pin to the 5VCC with a voltage divider to set the load line enable threshold and hysteresis.
27	VINMON	Power Stage Input Voltage Monitor. Connect this pin to the power stage input VIN with a voltage divider. The controller senses the voltage on this pin for power stage input voltage VIN detection.



No.	Name	Pin Function
28	SS	Soft Start. A capacitor connected between SS and FBRTN sets the soft start ramp-up time.
29	EAP	Non-inverting Input of the Error Amplifier. Connect a resistor between this pin and SS pin to set the droop (load line) function.
30	COMP	Output of Control Loop Error Amplifier.
31	FB	Inverting Input of the Error Amplifier.
32	FBRTN	Output Voltage Feedback Return. Inverting input to the differential voltage sense amplifier. FBRTN is the reference point in REFIN output voltage measurement. Connect this pin directly to the GPU output voltage feedback return sense point.
33	PROG3	<b>Function Setting Pin 3.</b> Connect this pin to the 5VCC with a voltage divider to set the phase reduction threshold and hysteresis.
34	PROG4	<b>Function Setting Pin 4.</b> Connect this pin to the 5VCC with a voltage divider to set the phase reduction threshold and hysteresis.
35	LPC	<b>Low Phase Count.</b> Connect a voltage divider to this pin to sets the operation phase number of Cold Boot mode and Warm Boot mode.
36	EN	<b>Enable.</b> Connect a resistor $R_{EN}$ (ranging from 30k $\Omega$ to 10k $\Omega$ ) from this pin to ground and place this resistor close to the controller. Do NOT use other resistance values other than the values specified here. Do not connect any capacitor directly to this pin. Refer to the typical application circuit, it is recommended to use a MOSFET with its drain connected to EN pin without a pull-up resistor for power sequence control. Do NOT connect EN pin directly to a voltage source for sequence control.
37	PSI	Power Saving Input. An input pin receiving power saving control signal from GPU.
38	PGOOD	Power Good Indication. Connect this pin to a voltage source with a pull-up resistor.
39	VID	VID. PWMVID input pin.
40	REFADJ	Reference Adjustment. PWMVID output pin. Connect this pin with an RC integrator to generate REFIN voltage.
Exposed Pad		<b>Ground.</b> The exposed pad is the ground of logic control circuits, it must be soldered to a large PCB and connected to GND.



# Functional Block Diagram





#### Power On Reset (POR)

Figure 1 shows the power ready detection circuit. The 5VCC voltage is monitored for power on reset with typically 4.3V threshold at its rising edge. When 5VCC is ready, the controller waits for EN to start up. When EN pin is driven above 0.4V, the controller begins its start up sequence. When EN pin is driven below 0.2V, the controller will be turned off, and it will clear all fault states to prepare to next soft-start once the controller is re-enabled.

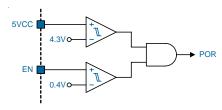


Figure 1. Circuit of Power Ready Detection

#### **Power Input Monitor**

VINMON is the power stage input voltage sense pin. Connect this pin to power stage input voltage (VIN) with a voltage divider and always keep VINMON of power stage input voltage. When VINMON less than typically 0.5V at POR, the uP9511R will forces starts up at single phase and disables the cold boot, warm boot, PSI and auto-phase function. Once this condition is triggered, it can only be reset by re-POR or EN restart.

#### Phase Number of Operation (Hardware Programming)

The uP9511R supports 8/7/6/5/4/3/2/1-phase operation. The maximum phase number of operation is determined by checking the status of ISENx pins when power on reset. Normally, uP9511R is 8-phase operation. Pull ISEN8 to 5VCC with a  $100k\Omega$  for 7-phase operation; Pull ISEN7 to 5VCC with a  $100k\Omega$  for 6-phase operation and so on. When operating in 7-phase, PWM8 outputs are set to high impedance; in 6-phase, PWM[8:7] outputs are set to high impedance and so on. The maximum phase number of operation is decided and latched at each POR rising edge. The unused ISENx pins and PWMx pins can be left floating.

#### **Operation Frequency**

The phase switching frequency of the uP9511R is set by an external resistor connected between PROG6 pin and GND. Table 1 lists the operation frequency and the recommended resistor  $R_{\text{PROG6}}$  value.

Table 1. Operation Frequency and Recommended R PROGE

Switching Frequency (kHz)	$ \begin{array}{c} \text{Recommended R}_{\text{\tiny PROG6}} \text{ Resistor} \\ \text{(k}\Omega) \end{array} $
200	51
300	33
400	24
500	20
600	16

#### **Power Saving Mode**

The uP9511R provides power saving features for platform designers to program platform specific power saving configuration. There are three operation modes: Full-Phase mode, Auto-Phase mode, and Low-Phase mode. The uP9511R switches between these three operation modes according to the input voltage level of the PSI pin. Figure 2 shows typical PSI application circuit, and table 2 shows recommended PSI setting voltage level of three operation modes. In low-phase mode, it can separate into Cold Boot Mode and Warm Boot Mode. The operation phase number of Cold Boot Mode and Warm Boot Mode is determined by LPC pin. In auto-phase mode, the operation phase number will auto increasing/reducing according to output loading. In Full-Phase mode, the maximum phase number of operation is determined by checking the status of ISENx pins when POR.

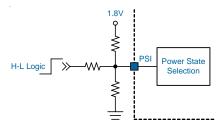


Figure 2. PSI application circuit

Table 2. Operation Mode and recommended V<sub>pq1</sub>

Operation Mode	Recommended Voltage Setting at PSI
Full-Phase Mode	1.8V
Auto-Phase Mode	1V
Low-Phase Mode	GND

#### **Auto-Phase Shedding**

The uP9511R provide Auto-Phase Shedding function to reduce the switching and conduction losses at light load condition and enable high efficiency over a wide range of output current. Auto-Phase Shedding function is activated by two conditions:

- 1. PSI voltage stays at "Auto-Phase Mode".
- 2. After PGOOD goes high, VID pin received the PWM-VID input signal from GPU.

Once the Auto-Phase Shedding function activated, the uP9511R compares the  $\rm V_{IMON}$  with  $\rm V_{PROG1}/\rm V_{PROG2}/\rm V_{PROG3}/\rm V_{PROG4}$  to decide the operation phase number dynamically. Connect each PROGx pins to 5VCC with a voltage divider to set the threshold and hysteresis. The threshold and the hysteresis can be calculated as:

$$V_{PROGx} = \frac{R_{BOT}}{R_{TOP} + R_{BOT}} \times 5V_{CC} = \left(\frac{I_{OUT} \times \frac{R_{DC}}{N}}{R_{SUM}}\right) \times R_{IMON} + 0.6$$



$$V_{PROGx\_Hys} = 10uA \times (R_{TOP} \parallel R_{BOT}) = \left(\frac{Iout\_Hys}{R_{SUM}} \times \frac{R_{DC}}{N}\right) \times R_{IMON}$$

Where  $\rm R_{TOP}$  is the resistor connects from 5VCC to PROGX pin, and  $\rm R_{BOT}$  is the resistor connects from PROGX pin to GND.

If  $V_{IMON} < V_{PROG1}$ , uP9511R operates in single phase; if  $V_{PROG1} < V_{IMON} < V_{PROG2}$ , uP9511R operates in dual phase; if  $V_{PROG2} < V_{IMON} < V_{PROG3}$ , uP9511R operates in four phase; if  $V_{PROG3} < V_{IMON} < V_{PROG3}$ , uP9511R operates in six phase; if  $V_{IMON} > V_{PROG4}$ , uP9511R operates in 8 phase. The uP9511R always keeps all-of-phase interleaved operation. When setting PROG1, PROG2, PROG3 and PROG4, always keep  $V_{PROG1} < V_{PROG2} < V_{PROG3} < V_{PROG4}$ . Violating this rule may lead to unknown status and should be avoided. Short the PROG1, PROG2, PROG3 and PROG4 to GND to disable the auto-phase mode.

# number of Cold Boot Mode and Warm Boot Mode. When PSI=Low and uP9511R first boots up (first time of 5VCC and EN goes high), controller will enter to Cold Boot Mode. Except the first boot up, when PSI=Low state and controller power up by EN control, then uP9511R will enter to Warm Boot Mode. Connect LPC pin to 5VCC with a voltage divider (Figure 3) to set the operation phase number of Cold Boot Mode and Warm Boot Mode. Figure 4 shows all the power states of uP9511R under each combination of 5VCC/EN/PSI/VID signal. Table 3 shows the recommended resistance

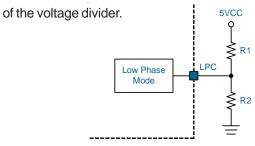


Figure 3. Circuit of LPC Setting

#### **Cold Boot and Warm Boot**

The uP9511R features programmable operation phase

Table 3. Recommended resistance of Cold Boot mode and Warm Boot mode

		Warm Boot Phase Count ( $k\Omega$ )									
V <sub>LPC</sub> = % of 5VCC	Cold Boot Phase Count	1-phase		2-phase		3-phase		4-phase		5-phase	
		R1	R2	R1	R2	R1	R2	R1	R2	R1	R2
40.63%	1-phase	4.92	3.37	24.61	16.84	44.3	30.32	73.84	50.53	147.67	101.06
46.88%	2-phase	4.27	3.77	21.33	18.83	38.4	33.89	63.99	56.48	127.99	112.95
53.13%	3-phase	3.76	4.27	18.82	21.34	33.88	38.4	56.47	64.01	112.93	128.01
59.38%	4-phase	3.37	4.92	16.84	24.62	30.31	44.31	50.52	73.86	101.04	147.71
65.63%	5-phase	3.05	5.82	15.24	29.1	27.43	52.37	45.71	87.29	91.42	174.57
71.88%	6-phase	2.78	7.11	13.91	35.56	25.04	64.01	41.74	106.69	83.47	213.37
78.13%	7-phase	2.56	9.14	12.8	45.72	23.04	82.3	38.4	137.17	76.8	274.35
84.38%	8-phase	2.37	12.8	11.85	64.02	21.33	115.24	35.55	192.06	71.11	384.12

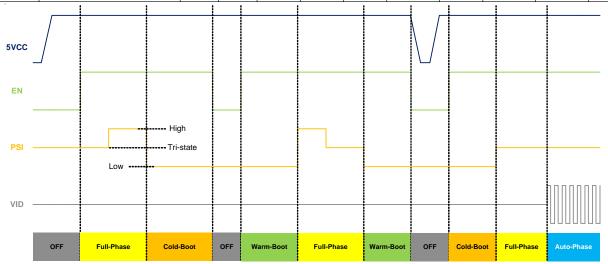


Figure 4. Power States of uP9511R



#### **Total Load Current Sense**

The uP9511R uses a low input offset current sense amplifier (CSA) to sense the total load current flowing through inductors for droop function by CSPSUM and CSNSUM as shown in Figure 5.

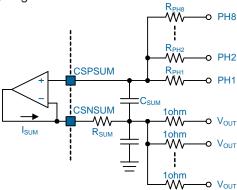


Figure 5. Total Load Current Sense

The voltage across  $C_{\text{SUM}}$  is proportional to the total load current, and the output current of  $\text{CSA}(I_{\text{SUM}})$  is also proportional to the total load current of the voltage regulator. The sensed current  $I_{\text{SUM}}$  represents the total output current of the regulator, and it is directly used for droop function, total output over current protection and auto-phase function.  $I_{\text{SUM}}$  is calculated as follows.

$$I_{SUM} = \frac{I_{OUT} \times \frac{R_{DC}}{N}}{R_{SUM}}$$

In this inductor current sensing topology,  $R_{PH}$  and  $C_{SUM}$  must be selected according to the equation below:

$$k \times \frac{L}{R_{DC}} = \frac{R_{PH} \times C_{SUM}}{N}$$

where  $R_{\text{DC}}$  is the DCR of the output inductor L, N is the operation phase number. Theoretically, k should be equal to 1 to sense the instantaneous total load current. But in real application, k is usually between 1.2 to 1.8 for better load transient response. Note that the resistance value of  $R_{\text{SUM}}$  must be less than  $2k\Omega$  to ensure the current sensing circuit in normal operation.

#### Voltage Control Loop

Figure 6 illustrates the voltage control loop of the uP9511R. FB and EAP are negative and positive inputs of the Error Amplifier respectively. The Error Amplifier modulates the COMP voltage  $V_{\text{COMP}}$  and the duty cycle of buck converter to force FB voltage VFB follows  $V_{\text{EAP}}.$  The sensed current signal ( $I_{\text{SUM}}$ ) is mirrored to the EAP pin and creates voltage at EAP pin as:

$$V_{EAP} = V_{SS} - I_{SUM} \times R_{LL}$$

where  $V_{\rm SS}$  is output of  $V_{\rm REFIN}$ ,  $I_{\rm SUM}$  is a current source proportional to output current, and  $R_{\rm LL}$  is an external resistor for adjusting load line slope. Therefore, the output voltage will be:

$$V_{OUT} = V_{SS} - \frac{I_{OUT} \times R_{DC} \times R_{LL}}{N \times R_{SUM}}$$

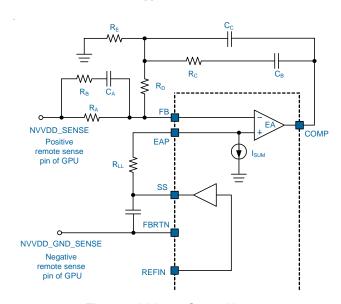


Figure 6. Voltage Control Loop

#### **Output Voltage Differential Sense**

The uP9511R uses differential sense by a high-gain low offset error amplifier for output voltage differential sense as shown in Figure 6. The GPU voltage is sensed by the FB and FBRTN pins. FB pin is connected to the positive remote sense pin NVVDD\_SENSE of the GPU via the resistor R<sub>FB</sub>. FBRTN pin is connected to the negative remote sense pin NVVDD\_GND\_SENSE of GPU directly.

#### Soft Start and Power Up Sequence

The uP9511R features a programmable soft start function to limits the prevent surge current from power supply input by a soft-start capacitor  $C_{\rm SS}$  connected between SS to FBRTN pin. Controller starts the soft-start process right on  $V_{\rm EN}{>}0.4V$  with typical 2ms initialization time  $(T_{\rm INIT}).$  When soft-start cycle is initiated, an internal current source charges the  $C_{\rm SS}$  to  $V_{\rm REFIN}.$  The ramp up time (Tramp) during soft start period is determined by the internal current source and  $C_{\rm SS},$  and it can be calculated as below.

$$Tramp = \frac{V_{REFIN, BOOT} \times Css}{I_{SS}}$$

For example, suppose  $V_{REFIN,BOOT}$  = 0.9V,  $C_{SS}$  = 22nF,  $I_{SS}$  = 13uA, the ramp up time is around 1.5ms.

If there is no fault detected at the end of soft-start, the controller then asserts PGOOD when the output voltage reaches its target without delay. Figure 7 shows the soft-start sequence of the uP9511R.



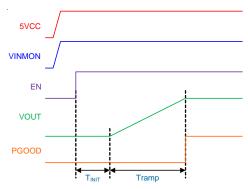


Figure 7. Power Up Sequence

#### **PWMVID Function**

The PWMVID signal from GPU is applied to the VID pin, which is the input pin of the internal buffer. This buffer plays the role of level shifting, and the output of this buffer is injected into the external RC integrator to generate REFIN voltage, which can be calculated as:

$$V_{RFFIN} =$$

$$V_{VREF} \times D \times \frac{R2/(R3 + R4 + R5)}{R1 + R2/(R3 + R4 + R5)} \times \frac{R4 + R5}{R3 + R4 + R5} +$$

$$V_{VREF} \times \frac{R1/(R3 + R4 + R5)}{R2 + R1/(R3 + R4 + R5)} \times \frac{R4 + R5}{R3 + R4 + R5}$$

where  $V_{REFIN}$  is the DC voltage of REFIN,  $V_{VREF}$  is the voltage of VREF (typically 2V), and D is the duty cycle of PWMVID input. The VREF pin is an internal LDO, therefore an output decoupling capacitor is required. Recommend connecting at least a 1uF capacitor from VREF pin to local GND.

# **Boot Voltage and Standby Mode**

The new generation PWMVID structure includes two operation modes other than normal operation: boot mode and standby mode. During boot mode, the GPU stops sending PWMVID signal and the input of the PWMVID buffer is floating. The REFADJ pin enters high impedance state after the VID pin enters tri-state region, and the REFIN voltage can then be calculated as:

$$V_{REFIN,BOOT} = V_{REF} \times \frac{R4 + R5}{R2 + R3 + R4 + R5}$$

During standby mode, other than GPU stopping the PWMVID transaction, an external system standby signal additionally controls the entry of standby mode. An additional external switch should be connected in parallel with the original PWMVID resistors as shown in Figure 8 to generate the standby mode voltage:

$$V_{REFIN,STDBY} =$$

$$V_{VREF} \times \frac{(R3 + R4 + R5) / / R_{STDBY}}{R2 + (R3 + R4 + R5) / / R_{STDBY}} \times \frac{R4 + R5}{R3 + R4 + R5}$$

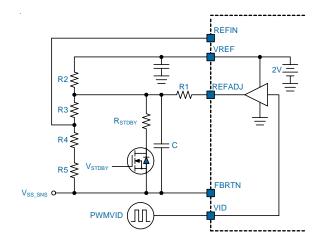


Figure 8. PWMVID structure

#### Load Line Enable Threshold

The uP9511R compares the  $V_{IMON}$  with  $V_{PROG5}$  to enable the Load Line function. Connect each PROG5 pins to 5VCC with a voltage divider to set the load line enable threshold and hysteresis. The load line enable threshold and the hysteresis is calculated as:

$$V_{PROG5} = \frac{R_{BOT}}{R_{TOP} + R_{BOT}} \times 5V_{CC} = \left(\frac{Iout \times \frac{R_{DC}}{N}}{R_{SUM}}\right) \times R_{IMON} + 0.6$$

$$V_{PROG5\_Hys} = 10uA \times \left(R_{TOP} \parallel R_{BOT}\right) = \left(\frac{Iout\_Hys}{\frac{R_{DC}}{N}}\right) \times R_{IMON}$$

Where  $R_{TOP}$  is the resistor connects from 5VCC to PROG5 pin, and  $R_{BOT}$  is the resistor connects from PROG5 pin to GND.

#### **Channel Current Balance**

The uP9511R senses phase currents for current balance by the means of on-resistance of power stage low-side MOSFETs when turning on as shown in Figure 9. The ISENx pins sense the corresponding phase current when the low-side MOSFETs are turned on.

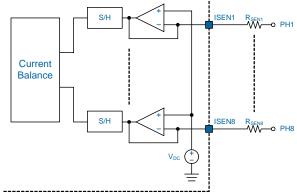


Figure 9. Current Balance Circuit



$$I_{SENX} = \frac{I_{PHX} \times R_{DS(ON)} + V_{DC}}{R_{SENX}}$$

where I<sub>SENX</sub> is the sample and held phase current signal, I<sub>PHX</sub> is phase current, R<sub>DS(ON)</sub> is the on-resistance of the low-side MOSFETs, and V<sub>DC</sub> = 30mV is an internal voltage source. In this current sense mechanism, the valley of the inductor current is sampled and held. Therefore, the equivalent sensed current can be described by the following equation:

$$I_{PHX\_SH} = I_{PHX\_AVG} - \frac{1}{2} \times \Delta I_{PHX}$$

The sensed current  $I_{PHX\_SH}$  is mirrored to the current balance circuit, comparing between each other, and generating current adjusting signals for each phase. The current balance circuit increases the duty cycle of the phase whose phase current is smaller than others and decrease the duty cycle of the phase whose phase current is larger than others.

#### **Channel Current Limit**

The uP9511R adopts channel valley current limit function to avoid catastrophic damage to power stage components. The uP9511R monitors the sensed current at ISENx pins and if the sensed  $I_{\text{SEN[N]}}$  of any phase exceeds the channel current limit threshold, the channel current limit function activates. The resistor  $R_{\text{EN}}$  connected between EN and ground determines the channel current limit the threshold. According the mentioned current sense equation, the channel current limit equation can be written as:

$$I_{MAX\_CH} = \frac{\frac{1500 \, mV}{R_{EN}(k\Omega)} \times R_{ISENX} \times \frac{10}{9} - V_{DC}}{R_{DS(ON)}}$$

where 1500mV/R<sub>EN</sub> denotes the internal CL\_CH threshold current, R<sub>EN</sub> is the EN pin to ground resistor in K $\Omega$  (e.g. R<sub>EN</sub> = 30k $\Omega$ , CL\_CH = 50uA), R<sub>ISENX</sub> is the external sensing resistor connected at ISENx pins, V<sub>DC</sub> is an internal 30mV voltage source, and R<sub>DS(ON)</sub> is the on-resistance of the low-side MOSFETs of the power stage in m $\Omega$ . Once the perphase current exceeds CL\_CH threshold, the per-phase output inductor current is limited to an average current. If a continuous over load event may lead the output voltage drop and eventually trigger under voltage protection and shuts down the uP9511R.

#### **Enable Sequence Control**

The EN pin controls the enable and disable of this device. The resistor  $R_{\text{EN}}$  connected between EN pin to ground is also used to implement this function. It is recommended to use a MOSFET with its drain connected to EN pin without pull up resistor for power sequence control as shown in Figure 10. Do NOT connect EN pin directly to a voltage source.

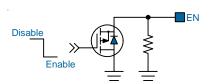


Figure 10. Enable Sequence Control

#### **Total Output Current Protection**

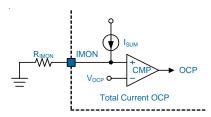


Figure 11. Total Output Current Protection

The uP9511R provides total current OCP as shown in Figure 11. The sensed current  $\rm I_{SUM}$  is mirrored internally and fed to IMON pin. A resistor  $\rm R_{IMON}$  is connected from IMON pin to GND. This current flows through the resistor  $\rm R_{IMON}$ , creating voltage drop across it. As the total load current increases, the voltage on IMON pin ( $\rm V_{IMON}$ ) increases proportionally. When the IMON pin voltage is greater than  $\rm V_{OCP}$ , the OCP will be triggered. Once OCP is triggered, it will be latched. Only re-start up can release the latch. The uP9511R will turn off both high-side and low-side MOSFETs of all channels. The total OCP level is changed per actual operating phase number. Table 4 shows the relationship between total OCP levels ( $\rm V_{OCP}$ ) and operating phase number. The total output current ( $\rm I_{OUT\_MAX}$ ) of triggered OCP is calculated as :

$$I_{OUT\_MAX} = \frac{V_{OCP} - 0.6V}{R_{IMON}} \times \frac{N \times R_{SUM}}{R_{Dc}}$$

The IMON pin has a 0.6V offset voltage, which means the IMON voltage increases from 0.6V as load current increases. The resistor  $R_{\rm IMON}$  must be in the range of 10K to 60K to let the 0.6V offset mechanism work normally.

Table 4. Operation Conditions and Total Output OCP Level (V<sub>OCP</sub>)

Operation Condition	OCP Level (V <sub>OCP</sub> )
8-Phase	3.0V
7-Phase	2.7V
6-Phase	2.4V
5-Phase	2.1V
4-Phase	1.8V
3-Phase	1.6V
2-Phase	1.3V
1-Phase	1.1V



# **Over Voltage Protection (OVP)**

The OVP is triggered if  $V_{FB} > 1.5 x \ V_{EAP}$  sustained 5us. When OVP is activated, the uP9511R turns on all low-side MOSFETs and turns off all high-side MOSFETs. The over voltage protection is a latch-off function and can only be reset by 5VCC re-POR or EN restart.

#### **Under Voltage Protection (UVP)**

The under voltage protection is triggered if V $_{\rm FB}$ < 0.5 x V $_{\rm EAP}$  sustained 5us. When UVP is activated, the uP9511R turns off all high-side and low-side MOSFETs. The under voltage protection is a latch-off function and can only be reset by 5VCC re-POR or EN restart.

### **Over Temperature Protection (OTP)**

The uP9511R monitors the temperature of itself. If the temperature exceeds typical 150°C, the uP9511R is forced into shutdown mode. The over temperature protection is a latch-off function and can only be reset by 5VCC re-POR or EN restart.



·	Absolute Maximum Rating
(Note 1)	<b>3</b>
Supply Input Voltage, 5VCC	0.3V to +6V
Other Pins	0.3V to +6V
Storage Temperature Range	
Junction Temperature	150°C
Lead Temperature (Soldering, 10 sec)	260°C
ESD Rating (Note 2)	
HBM (Human Body Mode)	2kV
MM (Machine Mode)	200V
	Thermal Information
Package Thermal Resistance (Note 3)	
VQFN5x5 - 40L θ <sub>1A</sub>	36°C/W
	3°C/W
Power Dissipation, $P_D @ T_A = 25^{\circ}C$	
VQFN5x5-40L	2.78W
	Recommended Operation Conditions
(Note 4)	•
Operating Junction Temperature Range	
Operating Ambient Temperature Range	
Supply Input Voltage, V <sub>CC5</sub>	4.5V to 5.5V

- **Note 1.** Stresses listed as the above *Absolute Maximum Ratings* may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- Note 2. Devices are ESD sensitive. Handling precaution recommended.
- Note 3.  $\theta_{JA}$  is measured in the natural convection at  $T_A = 25^{\circ}\text{C}$  on a low effective thermal conductivity test board of JEDEC 51-3 thermal measurement standard.
- Note 4. The device is not guaranteed to function outside its operating conditions.



# Electrical Characteristics

(5VCC = 5V,  $T_A = 25$ °C, unless otherwise specified)

SVCC POR Threshold   POR SVCC POR   4   4.3   4.5   V	Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
HYS <sub>SVCC.POR Hysteresis   HYS<sub>SVCC.POR</sub>   300 mV   Supply Current   I<sub>SVCC. EN high , No switching   4.5 mA   Shutdown Current   I<sub>SVC. EN bigh , No switching   250 uA   Power Stage Input Voltage Monitoring     No.7 2.6   V   V   V   V   V   V   V   V   V   </sub></sub></sub>	Supply Input			1			
HYS <sub>SVCC.POR Hysteresis   HYS<sub>SVCC.POR</sub>   300 mV   Supply Current   I<sub>SVCC. EN high , No switching   4.5 mA   Shutdown Current   I<sub>SVC. EN bigh , No switching   250 uA   Power Stage Input Voltage Monitoring     No.7 2.6   V   V   V   V   V   V   V   V   V   </sub></sub></sub>	5VCC POR Threshold	POR <sub>5VCC</sub>	5VCC rising	4	4.3	4.5	V
Supply Current         I <sub>svec</sub> EN high , No switching          4.5          mA           Shutdown Current         I <sub>so</sub> EN = 0V          250          uA           Power Stage Input Voltage Monitoring           VINIMON monitoring range         0.7          2.6         V           VINIMON Hysteresis         V <sub>VINIMON, Hysteresis</sub> 0.5          V           VINIMON Hysteresis         V <sub>VINIMON, Hysteresis</sub> 100          mV           Enable Control         USE           Logic Low Threshold         V <sub>L,EN</sub> 0.2         V           Logic High Threshold         V <sub>L,EN</sub> 0.4           V           VPREF Voltage         VREF Voltage         1.98         2         2.02         V           VREF Sourcing Current         I <sub>SEF</sub> 1.98         2         2.02         V           VREF Sourcing Current         I <sub>SEF</sub> 1.98         2         2.02         V           REFIN Disable Threshold         V <sub>REFN, D,DSS</sub> 0.1         V	5VCC POR Hysteresis				300		mV
Power Stage Input Voltage Monitoring	Supply Current				4.5		mA
VINMON monitoring range	Shutdown Current	I <sub>SD</sub>	EN = 0V		250		uA
VinMON Rising Threshold   Vindon   V	Power Stage Input Voltage Monitor	oring		•		•	
VinMON Hysteresis   Vinder Hysteresis   Vi	VINMON monitoring range			0.7		2.6	V
VinMON Hysteresis   Vinder Hysteresis   Vi	VINMON Rising Threshold	V <sub>VINMON</sub>			0.5		V
Enable Control   Logic Low Threshold   VI_LEN	VINMON Hysteresis				100		mV
Logic High Threshold   V   VREF Voltage	Enable Control			•			
Logic High Threshold   V   VREF Voltage	Logic Low Threshold	V <sub>IL_EN</sub>				0.2	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Logic High Threshold			0.4			V
VREF Sourcing Current   I	2V VREF Voltage			•			•
VREF Sourcing Current   I	VREF Voltage Accuracy	V <sub>REF</sub>		1.98	2	2.02	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	VREF Sourcing Current	_		10			mA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Referenece Input Voltage (REFIN	)		-			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	REFIN Disable Threshold	V <sub>REFIN_DSB</sub>				0.1	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	External Reference Voltage Range			0.2		2	V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	PWMVID Buffer			•	1		
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	VID input Low Level	V <sub>IL_VID</sub>				0.6	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	VID input High Level			1.2			V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	VID Tri-state Delay				100		ns
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	REFADJ Source Resistance	R <sub>BF_SRC</sub>	I <sub>SRC</sub> = 1mA		20		Ω
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	REFADJ Sink Resistance		I <sub>SINK</sub> = 1mA		20		Ω
Operation Frequency Accuraccy $R_{PROG6} = 33kΩ$ $270$ $300$ $330$ kHz       PROG6 Output Voltage      1.2      V       Soft-Start       Soft-Start Current     Iss     Normal(during soft-start period)      13 $13$	Oscillator						
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Operation Frequency Range	F <sub>sw</sub>		200		600	kHz
Soft-Start         Normal(during soft-start period)          13          uA           REFIN Transient          220	Operation Frequency Accuraccy		$R_{PROG6} = 33k\Omega$	270	300	330	kHz
Soft-Start Current Iss Normal(during soft-start period) 13 uA  REFIN Transient 220	PROG6 Output Voltage				1.2		V
Soft-Start Current Iss REFIN Transient 220	Soft-Start					•	-
REFIN Transient 220	Soft Stort Current	loo	Normal(during soft-start period)		13		^
Initialization Time T <sub>NIT</sub> EN high to Vout Start up from 0V 1.1 ms	Soit-Stait Current	ISS	REFIN Transient		220		uA
	Initialization Time	T <sub>INIT</sub>	EN high to Vout Start up from 0V		1.1		ms



# Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Voltage Error Amplifier						
Open Loop DC Gain	AO	Guaranteed by Design		70		dB
Gain-Bandwidth Product	GBW	Guaranteed by Design		10		MHz
Trans-conductance	GM			1500		uA / V
COMP Source Current	COMP_SRC			300		uA
COMP Sink Current	COMP_SNK			300		uA
FBRTN						
FBRTN Current	I <sub>FBRTN</sub>	EN = 1.4V, No Switching			500	uA
Current Sense Amplifier ( Total Current	Summing )			•		
Input Offset Voltage	V <sub>OFF_CSA</sub>		-1		1	mV
Max Sourcing Current	  SRC_CSA		200			uA
Current Sense Amplifier ( Current Balan	•			•		
Input Offset Voltage	V <sub>OFF_CSA</sub>		-1		1	mV
Max Sourcing Current	I <sub>SRC_CSA</sub>		200			uA
ISENx Voltage	V <sub>DC_CSA</sub>		25	30	35	mV
PWM Output						
Output Low Voltage	V <sub>PWM_L</sub>	I <sub>SNK</sub> = 4mA			0.2	V
Output Hight Voltage	V <sub>PWM_H</sub>	I <sub>SOURCE</sub> = 4mA	4.7			V
High Impedance State Leakage		V <sub>PWM</sub> = 0V	-1		0	uA
High Impedance State Leakage		V <sub>PWM</sub> = 5V	0		1	uA
Power Saving Input (PSI)						
		Full-Phase Mode	1.4			V
Power Saving Mode Logic	V <sub>PSI</sub>	Auto-Phase Mode	0.8		1.2	V
		Low-Phase Mode			0.4	V
Auto-Phase/Load Line						
Internal Sink Current	I <sub>SNK</sub>			10		uA
Current Monitoring for Droop/IMON						
Current Mirror Accuracy		I <sub>EAP</sub> /I <sub>MON</sub>	95	100	105	%
Offset Voltage	V <sub>IMON_OFS</sub>			0.6		V
Protection						
Channel Current Limit (CL_CH) Threshold	l <sub>oc_ch</sub>	$I_{SENx} > I_{CL\_CH}, R_{EN} = 30k\Omega$		50		uA
Total Current Protection (OCP) Threshold	V <sub>OCP</sub>	V <sub>IMON</sub> > V <sub>OCP</sub> , 8-phase mode		3		V
Under Voltage Protection (UVP) Threshold	V <sub>UVP</sub>	$V_{FB}/V_{EAP}$	40		50	%
Under Voltage Protection (UVP) Delay	T <sub>UVP</sub>			5		us

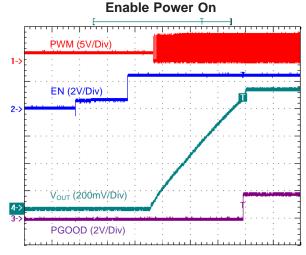


# Electrical Characteristics

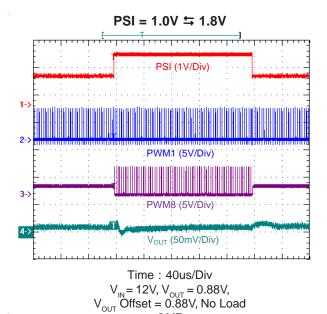
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit			
Protection (cont'd)									
Over Voltage Protection (OVP) Threshold	V <sub>OVP</sub>	V <sub>FB</sub> /V <sub>EAP</sub>	150			%			
Over Voltage Protection (OVP) Delay	T <sub>OVP</sub>			5		us			
Over Temperature Protection (OTP)	T <sub>OTP</sub>	Guaranteed by Design		150		°C			
Power Good Indicator									
PGOOD Output Low Level	V <sub>PG</sub>	I <sub>SINK</sub> = 4mA			0.3	V			
PGOOD Leakage Current	l <sub>PG_Leak</sub>	$V_{PG} = 5V$			0.2	uA			



# **Typical Operation Characteristics**



 $\label{eq:local_control_control} \mbox{Time : 400us/Div} \\ \mbox{V}_{\mbox{\tiny IN}} = \mbox{12V, V}_{\mbox{\tiny OUT}} = 0.88\mbox{V, No Load} \\ \mbox{}$ 



OVP

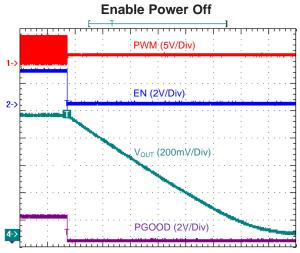
1->
PWM (5V/Div)

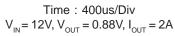
LG (10V/Div)

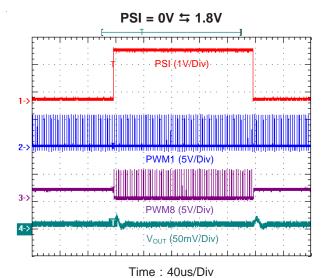
3->
FB (1V/Div)

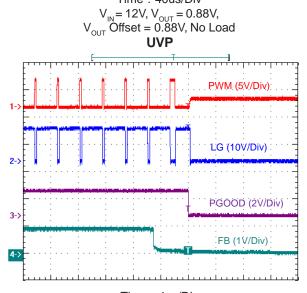
Time: 4us/Div

V<sub>IN</sub> = 12V, No Load



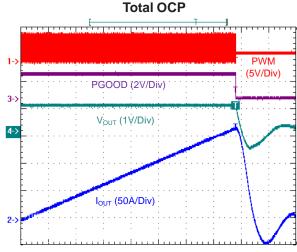




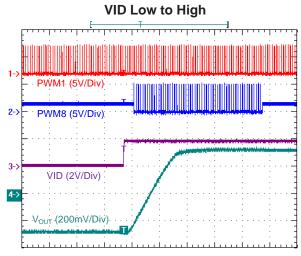




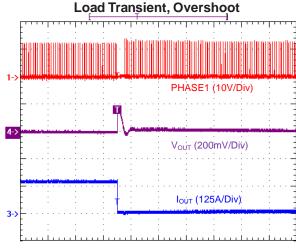
# **Typical Operation Characteristics**



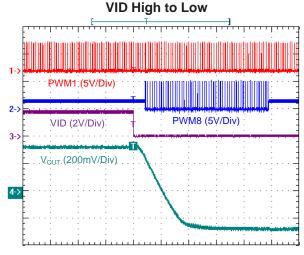
Time : 200us/Div  $V_{IN}$  = 12V,  $V_{OUT}$  = 0.88V,  $I_{OUT}$  = 160A



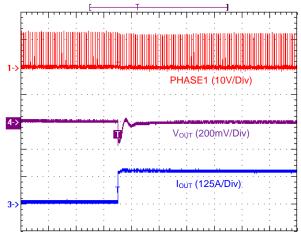
 $\label{eq:V_IN} \begin{aligned} &\text{Time: 40us/Div}\\ &\text{V}_{\text{IN}}\text{= 12V, V}_{\text{OUT}} = 0.88\text{V, V}_{\text{OUT}} \text{ Offset = 0.88V,}\\ &\text{PSI = 0V,Cold Boot 6 Phase, No Load} \end{aligned}$ 



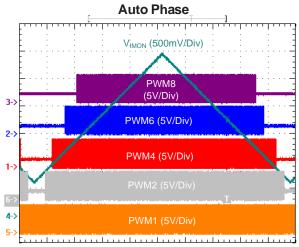
Time : 40us/Div  $V_{IN} = 12V, V_{OUT} = 0.88V, V_{OUT} Offset = 0.88V, PSI = 1.8V, I_{OUT} = 14A~160A$ 



Time: 40us/Div  $V_{IN} = 12$ V,  $V_{OUT} = 0.88$ V,  $V_{OUT}$  Offset = 0.88V, PSI = 0V,Cold Boot 6 Phase, No Load **Load Transient, Undershoot** 



Time : 40us/Div  $V_{IN} = 12$ V,  $V_{OUT} = 0.88$ V,  $V_{OUT}$  Offset = 0.88V, PSI = 1.8V,  $I_{OUT} = 14$ A $\sim 160$ A

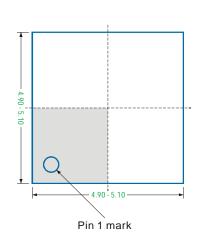


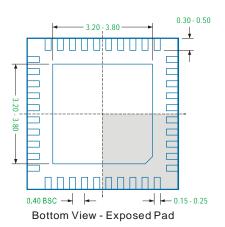
Time : 40 us/Div $V_{\text{IN}} = 12 \text{V}, V_{\text{OUT}} = 0.88 \text{V}, V_{\text{IMON}} = 0.6 - 3.0 \text{V}, \text{No Load}$ 



# Package Information

#### VQFN5x5 - 40L







# Note

1. Package Outline Unit Description:

BSC: Basic. Represents theoretical exact dimension or dimension target

MIN: Minimum dimension specified. MAX: Maximum dimension specified.

REF: Reference. Represents dimension for reference use only. This value is not a device specification.

TYP. Typical. Provided as a general value. This value is not a device specification.

2. Dimensions in Millimeters.

3. Drawing not to scale.

4. These dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm.



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